Absolute Maximum Ratings

Voltage Referenced to GND	
V+0.3V to +1	7V
V+0.3V to -1	7V
V+ to V0.3V to +1	7V
COM_, NO_, NC_, IN_ (Note 1) (V 2V) to (V+ + 2	2V)
or 30mA, whichever occurs f	irst
Continuous Current, Any Pin30r	nΑ
Peak Current, Any Pin	
(pulsed at 1ms, 10% duty cycle max)100r	nΑ

Continuous Power Dissipation ($T_A = +$	70°C)
Plastic DIP (derate 10.53mW/°C abo	ove+70°C)842mW
Narrow SO (derate 8.70mW/°C above	ve +70°C)696mW
CERDIP (derate 10.00mW/°C above	+70°C)800mW
TSSOP (derate 11.00mW/°C above	+70°C)879mW
Operating Temperature Ranges	
MAX394C_ P	0°C to +70°C
MAX394E_ P	40°C to +85°C
MAX394MJP	55°C to +125°C
Storage Temperature Range	
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on NC, NO, COM, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Electrical Characteristics—Dual Supplies

(V+ = 5V \pm 10%, V- = -5V \pm 10%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		TEMP. RANGE	MIN	TYP (Note 2)	MAX	UNITS			
SWITCH	SWITCH										
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}	(Note 3)			V-		V+	V			
		V+ = 4.5V, V- = -4.5V,	T _A =	C, E		20	35				
On-Resistance	Ross	V_{NC} or $V_{NO} = \pm 3.5V$,	+25°C	М		20	30	Ω			
CIT-I COISTAINC	R _{ON}	I _{COM} = 10mA, V _{INH} = 2.4V, V _{INL} = 0.8V	$T_A = T_{MIN}$ to T_{MAX}	C, E, M			45	32			
On-Resistance Match Between Channels	ΔR _{ON}	V_{NC} or $V_{NO} = \pm 3V$,	T _A = +25°C	C, E, M		0.5	2	Ω			
(Note 4)	ΔινοΝ	I _{COM} = 10mA, V+ = 5V, V- = -5V		C, E, M			4	22			
On-Resistance Flatness	$R_{FLAT(ON)} \begin{vmatrix} V_{NC} \text{ or } V_{NO} = 3V, 0V, \\ -3V; I_{COM} = 10mA, \\ V+ = 5V; V- = -5V \end{vmatrix}$	110	T _A = +25°C	C, E, M			4	Э			
(Note 4)			FLAT(ON)	'`FLAT(ON)	'`FLAT(ON)		$T_A = T_{MIN}$ to T_{MAX}	C, E, M			6
		\\ - \.4.5\\	T _A =	C, E	-0.2	-0.01	+0.2				
NC or NO Off-Leakage	NC(OFF)	$V_{COM} = \pm 4.5V,$ V_{NC} or $V_{NO} = \pm 4.5V,$	+25°C	M	-0.1	-0.01	+0.1	nA			
Current (Note 5)	I _{NO(OFF)}	V _{NC} or v _{NO} – ±4.5v, V+ = 5.5V. V- = -5.5V	$T_A = T_{MIN}$	C, E	-2.5		+2.5	11/4			
	140(011)		to T _{MAX}	M	-20		+20				
		\\ - \4.5\\	T _A =	C, E	-0.4	-0.04	+0.4				
COM Leakage Current	loowon	$V_{COM} = \pm 4.5V,$ V_{NC} or $V_{NO} = \pm 4.5V,$ $V_{+} = 5.5V, V_{-} = -5.5V$	+25°C	М	-0.2	-0.04	+0.2	nA			
(Note 5)	ICOM(ON)		$T_A = T_{MIN}$	C, E	-5.0		+5.0	11/5			
	0.50, 0.50		to T _{MAX}	M	-20		+20				

Electrical Characteristics—Dual Supplies (continued)

(V+ = 5V \pm 10%, V- = -5V \pm 10%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT							
Input Current with Input Voltage High	I _{INH}	V _{IN} = 2.4V, all others = 0).8V	-1.0	+0.005	+1.0	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0.8V, all others = 2	2.4V	-1.0	+0.005	+1.0	μA
Logic High Input Voltage	V _{A_H}		$T_A = T_{MIN}$ to T_{MAX}	2.4			V
Logic Low Input Voltage	V _{A_L}		$T_A = T_{MIN}$ to T_{MAX}			0.8	V
DYNAMIC							
Turn-On Time	t	V _{COM} = 3V, Figure 2	T _A = +25°C		82	130	ns
rum-on nine	t _{ON}	vCOM - 3v, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			175	113
Turn-Off Time	t _{OFF}	V _{COM} = 3V, Figure 2	T _A = +25°C		57	75	ns
Tuni on Timo	OFF	VCOM OV, 1 Iguro 2	$T_A = T_{MIN}$ to T_{MAX}			100	110
Break-Before-Make Time Delay (Note 3)	t _D	Figure 5	T _A = +25°C	2	10		ns
Charge Injection (Note 3)	V _{CTE}	CL = 1.0nF, VGEN = 0V, RGEN = 0Ω , Figure 6	T _A = +25°C		5	10	рС
Off-Isolation (Note 6)	V _{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 3	T _A = +25°C		66		dBm
Crosstalk (Note 7)	V _{CT}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 8	T _A = +25°C		88		dBm
Off-Capacitance	C _{OFF}	f = 1MHz, Figure 3	T _A = +25°C		12		pF
COM Off-Capacitance	C _{COM(OFF)}	f = 1MHz, Figure 3	T _A = +25°C		12		pF
Channel On-Capacitance	C _{COM(ON)}	f = 1MHz, Figure 4	T _A = +25°C		39		pF
SUPPLY							
Power-Supply Range				±2.4		±8	V
Positive Supply Current	l+	All channels on or off, V+ = 5.5V, V- = -5.5V, V _{IN} = 0V or V+		-1.0	+0.06	+1.0	μΑ
Negative Supply Current	I-	All channels on or off, V+ = 5.5V, V- = -5.5V, V _I	N = 0V or V+	-1.0	-0.01	+1.0	μА

Electrical Characteristics—Single +5V Supply

(V+ = 5V \pm 10%, V- = 0V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		TEMP. RANGE	MIN	TYP (Note 2)	MAX	UNITS
SWITCH								
Analog Signal Range	$V_{\text{COM}}, V_{\text{NO}}, V_{\text{NC}}$	(Note 3)			0V		V+	V
		V+ = 5.0V, V- = 0V,	T _A = +25°C	C, E		25	65	
On-Resistance	R _{ON}	V_{NC} or $V_{NO} = 3.5V$, $I_{COM} = 1.0$ mA,	1A - +25 C	М			60	Ω
		V _{INL} = 0.8V to	$T_A = T_{MIN}$ to T_{MAX}	C, E, M			75	
On-Resistance Match		V_{NC} or $V_{NO} = 3V$,	T _A = +25°C	C, E, M		0.5	2	
Between Channels (Note 4)	ΔR _{ON}	I _{COM} = 1.0mA, V+ = 5V	$T_A = T_{MIN}$	C, E, M			4	Ω
0.0.14		V _{NC} or V _{NO} = 3V, 2V,	T _A = +25°C	C, E, M			6	
On-Resistance Flatness (Note 4)	R _{FLAT(ON)}	1V; I _{COM} = 1.0mA; V+ = 5V; V- = 0V	$T_A = T_{MIN}$ to T_{MAX}	C, E, M			8	Ω
			T = 125°C	C, E	-0.2	-0.01	+0.2	
NC or NO Off-Leakage	NC(OFF)	$V_{COM} = 0V$, V_{NC} or $V_{NO} = 4.5V$,	T _A = +25°C	M	-0.1	-0.01	+0.1	nA
Current (Note 8)	I _{NO(OFF)}	V _{NC} or V _{NO} = 4.5V, V+ = 5.5V, V- = 0V	$T_A = T_{MIN}$	C, E	-2.5		+2.5] 11A
	NO(OFF)		to T _{MAX}	M	-20		+20	
		_ 4 5 \ /	T _A = +25°C	C, E	-0.4	-0.04	+0.4	
COM Leakage Current	I _{COM(ON)}	$V_{COM} = 4.5V,$ V_{NC} or $V_{NO} = 4.5V,$, ,	M	-0.2	-0.04	+0.2	nA
(Note 8)	COM(ON)	V+ = 5.5V, V- = 0V	$T_A = T_{MIN}$	C, E	-5.0		+5.0	""
			to T _{MAX}	M	-20	-	+20	
DIGITAL LOGIC INPUT	1	T		1				T
Input Current with Input Voltage High	I _{INH}	V _{IN} = 2.4V, all others = 0.8V			-1.0	+0.005	+1.0	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0.8V, all others :	= 2.4V		-1.0	+0.005	+1.0	μA

Electrical Characteristics—Single +5V Supply (continued)

(V+ = 5V \pm 10%, V- = 0V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
DYNAMIC								
Turn On Time (Note 2)	+	\/ = 2\/ Figure 2	T _A = +25°C		160	250	20	
Turn-On Time (Note 3)	ton	V _{COM} = 3V, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			300	ns	
T Off Time - (NI-4- 2)	+	\/ - 2\/ F: 0	TA = +25°C		60	125		
Turn-Off Time (Note 3)	t _{OFF}	V _{COM} = 3V, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			175	ns	
Break-Before-Make Time Delay (Note 3)	t _D		T _A = +25°C	5	20		ns	
Charge Injection (Note 3)	V _{CTE}	$C_L = 1.0$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ Ω	T _A = +25°C		3	5	рС	
SUPPLY								
Power-Supply Range	V+					16	V	
Positive Supply Current	l+	All channels on or off, V _{IN} = 0V or V+, V+ = 5.5V, V- = 0V		-1.0	+0.01	+1.0	μA	
Negative Supply Current	I-	All channels on or off, V _{IN} = 0V or V+, V+ = 5.5V, V- = 0V		-1.0	-0.01	+1.0	μA	

Electrical Characteristics—Single +3.3V Supply

(V+ = 3.0V to 3.6V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		TEMP. RANGE	MIN	TYP (Note 2)	MAX	UNITS
SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}	(Note 3)			0		V+	V
		I _{COM} = 1.0mA, V _{INH} = 2.4V,		C, E		75	185	
On-Resistance	R _{ON}		T _A = +25°C	М			175	Ω
	V		$T_A = T_{MIN}$ to T_{MAX}	C, E, M			250	
			T _A = +25°C	C, E	-0.2	-0.01	+0.2	
NC or NO Off-Leakage	INC(OFF)	$V_{COM} = 0V,$ V_{NC} or $V_{NO} = 3V, V+$	1A - +25 C	M	-0.1	-0.01	+0.1	nA
Current (Note 8)	l _{NO(OFF)}	= 3.6V, V- = 0V	$T_A = T_{MIN}$	C, E	-2.5		+2.5	II/A
	NO(OFF)	0.00, 0	to T _{MAX}	M	-5.0		+5.0	
COM Leakage Current (Note 8)		.,	T _A = +25°C	C, E	-0.4	-0.04	+0.4	
	1	$V_{COM} = 3V$,	1A - F25 C	M	-0.2	-0.04	+0.2	nA
	ICOM(ON)	V _{NC} or V _{NO} = 3V, V+ = 3.6V. V- = 0V	$T_A = T_{MIN}$	C, E	-5.0		+5.0] 11/4
		to T _{MAX}		M	-20.0		+20.0	

Electrical Characteristics—Single +3.3V Supply (continued)

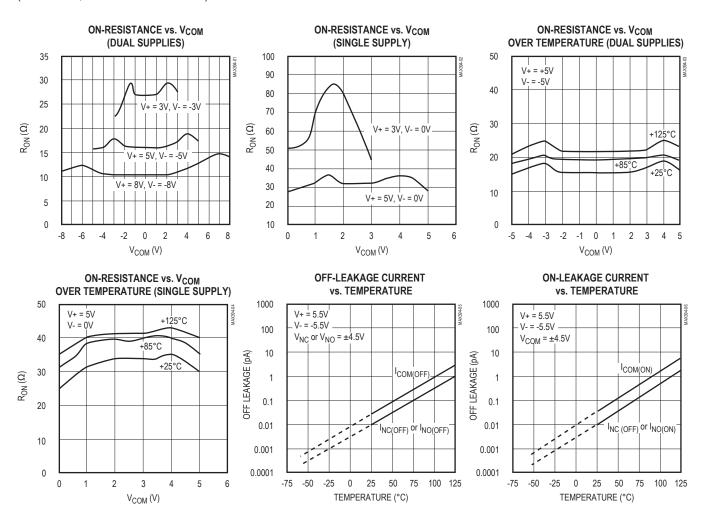
(V+ = 3.0V to 3.6V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT							
Input Current with Input Voltage High	I _{INH}	V _{IN} = 2.4V, all others = 0.8	V _{IN} = 2.4V, all others = 0.8V		+0.005	+1.0	μA
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0.8V, all others = 2.4	V _{IN} = 0.8V, all others = 2.4V		+0.005	+1.0	μA
DYNAMIC	DYNAMIC						
Turn-On Time (Note 3)	t _{ON}	V _{COM} = 1.5V, Figure 2	T _A = +25°C			400	ns
Turn-Off Time (Note 3)	t _{OFF}	V _{COM} = 1.5V, Figure 2	T _A = +25°C			150	ns
Break-Before-Make Delay (Note 3)	t _D	Figure 5	T _A = +25°C	5	20		ns
Charge Injection (Note 3)	V _{CTE}	$C_L = 1.0$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0\Omega$, Figure 6	T _A = +25°C		1	5	рС
SUPPLY							
Power-Supply Range	V+			2.7		16	V
Positive Supply Current	l+	All channels on or off, V _{IN} = 0V or V+, V+ = 3.6V, V- = 0V		-1.0	+0.01	+1.0	μA
Negative Supply Current	I-	All channels on or off, V _{IN} V+ = 3.6V, V- = 0V	= 0V or V+,	-1.0	-0.01	+1.0	μA

- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- Note 4: ΔR_{ON} = ΔR_{ON(max)} ΔR_{ON(min)}. On-resistance match between channels and flatness are guaranteed only with specified voltages. Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.
- Note 5: Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at room temperature.
- Note 6: See Figure 6. Off-isolation = $20log_{10} V_{COM}/V_{NC}$ or V_{NO} , V_{COM} = output, V_{NC} or V_{NO} = input to off switch.
- Note 7: Between any two switches. See Figure 3.
- Note 8: Leakage testing at single supply is guaranteed by testing with dual supplies.

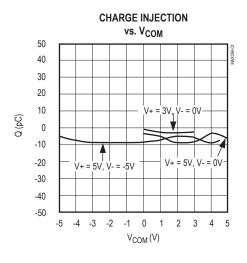
Typical Operating Characteristics

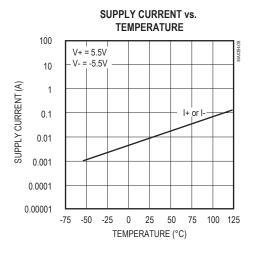
(TA = +25°C, unless otherwise noted.)

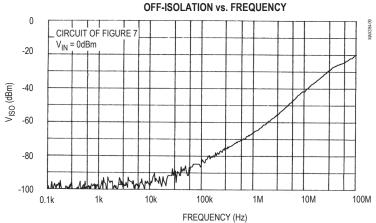


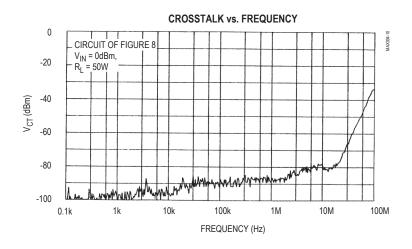
Typical Operating Characteristics (continued)

(TA = +25°C, unless otherwise noted.)









Pin Description

PIN	NAME	FUNCTION		
1, 10, 11, 20	IN1–IN4	Logic-Level Inputs		
2, 9, 12, 19	NO1-NO4	Normally Open Switches		
3, 8, 13, 18	COM1-COM4	Common Switch Poles		
4, 7,14, 17	NC1-NC4	Normally Closed Switches		
5	V-	Negative Power Supply		
6	GND	Ground		
15	N.C.	Not Internally Connected		
16	V+	Positive Power Supply		

Applications Information

Operation with Supply Voltages Other than ±5V

The MAX394 switch operates with $\pm 2.7V$ to $\pm 8V$ bipolar supplies and a $\pm 2.7V$ to $\pm 15V$ single supply. In either case, analog signals ranging from V+ to V- can be switched. The *Typical Operating Characteristics* graphs show the typical on-resistance variation with analog signal and supply voltage. The usual on-resistance temperature coefficient is 0.5%°C (typ).

Power-Supply Sequencing and Overvoltage Protection

Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the device. Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+, followed by V- (when using split supplies) before applying analog signals or logic inputs, especially if the analog or logic signals are not current-limited. If this sequencing is not possible and if the analog or logic inputs are not current-limited to less than 30mA, add a single diode (D1) for single-supply operation (Figure 1). If using dual

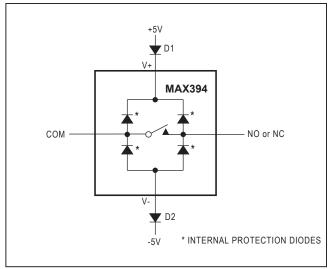


Figure 1. Overvoltage Protection Using Blocking Diodes

supplies or if the analog signal can dip below ground in single-supply operation, add two small signal diodes (D1, D2), as shown in Figure 1. Adding protection diodes reduces the analog signal range to a diode drop above V- for D2. Leakage is not affected by adding the diodes. On-resistance increases by a small amount at low supply voltages. Maximum supply voltage (V- to V+) must not exceed 17V.

Adding diodes D1 and D2 also protects against some overvoltage situations. With the circuit of $\frac{Figure\ 1}{Figure\ 1}$, if the supply voltage is below the absolute maximum rating and if a fault voltage up to the absolute maximum rating is applied to an analog signal pin, no damage will result. For example, with $\pm5V$ supplies, analog signals up to $\pm8.5V$ will not damage the circuit of $\frac{Figure\ 1}{Figure\ 1}$. If only a single fault signal is present, the fault voltage can go to +12V or -12V without damage.

Test Circuits/Timing Diagrams

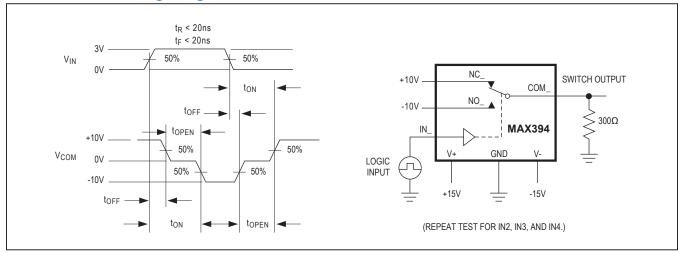


Figure 2. Switching-Time Test Circuit

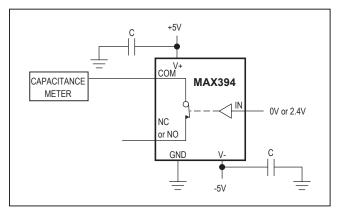


Figure 3. Channel Off-Capacitance

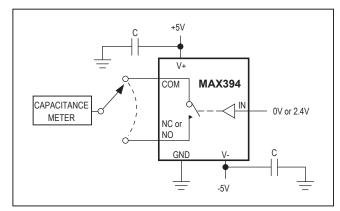


Figure 4. Channel On-Capacitance

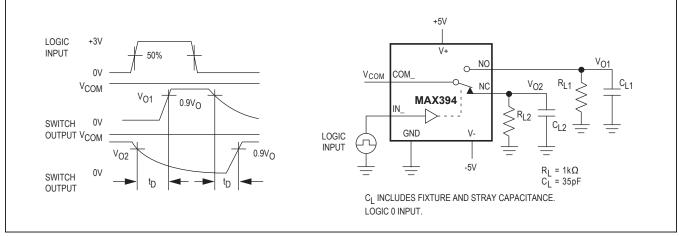


Figure 5. Break-Before-Make Delay

Test Circuits/Timing Diagrams (continued)

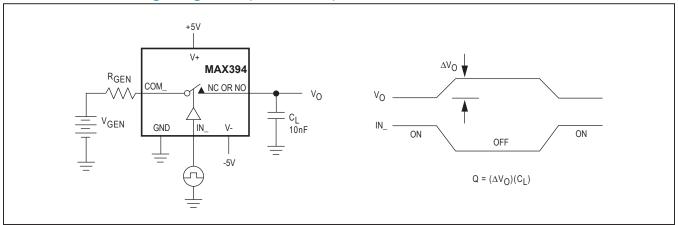


Figure 6. Charge Injection

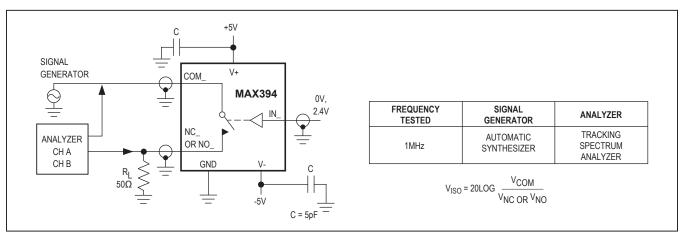


Figure 7. Off-Isolation

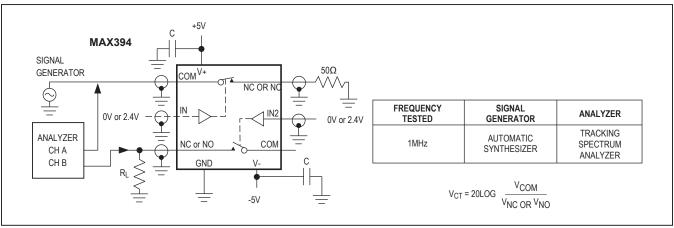
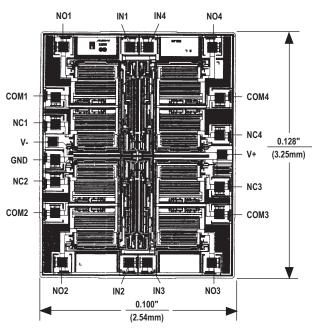


Figure 8. Crosstalk Test Circuit

Chip Topography



SUBSTRATE IS CONNECTED TO V+ TRANSISTOR COUNT: 137

Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
20 Plastic DIP	P20-4	<u>21-0043</u>
20 Wide SO	W26-1	21-0042
20 TSSOP	U20-2	21-0066
20 CERDIP	J20-2	<u>21-0335</u>
20 SSOP	A20+1	<u>21-0056</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
2	9/08	Added information for rugged plastic product.	1
3	1/21	Added new packages to <i>Ordering Information</i> , added SSOP to <i>Pin Configuration</i> and <i>Package Information</i> .	1, 12

